

# MOS FIELD EFFECT TRANSISTOR **2SJ600**

# SWITCHING P-CHANNEL POWER MOS FET INDUSTRIAL USE

# DESCRIPTION

The 2SJ600 is P-channel MOS Field Effect Transistor designed for solenoid, motor and lamp driver.

### FEATURES

- Low on-state resistance:  $R_{DS(on)1} = 50 \text{ m}\Omega \text{ MAX}. \text{ (Vgs} = -10 \text{ V}, \text{ Id} = -13 \text{ A})$  $R_{DS(on)2} = 79 \text{ m}\Omega \text{ MAX}. \text{ (Vgs} = -4.0 \text{ V}, \text{ Id} = -13 \text{ A})$
- Low Ciss: Ciss = 1900 pF TYP.
- Built-in gate protection diode
- TO-251/TO-252 package

### ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Drain to Source Voltage (Vgs = 0 V)	VDSS	-60	V
Gate to Source Voltage (VDS = 0 V)	Vgss	∓20	V
Drain Current (DC) (Tc = 25°C)	D(DC)	∓25	А
Drain Current (pulse) Note1	D(pulse)	<del>7</del> 70	А
Total Power Dissipation ( $Tc = 25^{\circ}C$ )	P⊤	45	W
Total Power Dissipation (T <sub>A</sub> = 25°C)	P⊤	1.0	W
Channel Temperature	Tch	150	°C
Storage Temperature	Tstg	–55 to +150	°C
Single Avalanche Current Note2	las	-25	А
Single Avalanche Energy Note2	Eas	62.5	mJ

ORDERING INFORMATION

PART NUMBER	PACKAGE
2SJ600	TO-251
2SJ600-Z	TO-252

(TO-251)



(TO-252)



Notes 1.  $PW \le 10 \ \mu s$ , Duty cycle  $\le 1\%$ 

**2.** Starting  $T_{ch} = 25^{\circ}C$ ,  $R_G = 25 \Omega$ ,  $V_{GS} = -20 V \rightarrow 0 V$ 

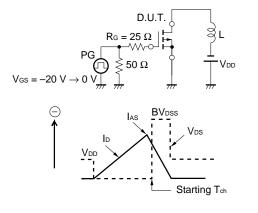
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# ELECTRICAL CHARACTERISTICS (TA = 25°C)

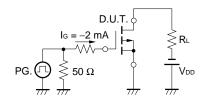
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	IDSS	$V_{DS} = -60 V, V_{GS} = 0 V$			-10	μA
Gate Leakage Current	lgss	$V_{GS} = \overline{+}20 V$ , $V_{DS} = 0 V$			<b>∓</b> 10	μA
Gate Cut-off Voltage	VGS(off)	$V_{DS} = -10 V$ , $I_{D} = -1 mA$	1.5	2.0	2.5	V
Forward Transfer Admittance	y <sub>fs</sub>	$V_{DS} = -10 V$ , $I_{D} = -13 A$	10	20		s
Drain to Source On-state Resistance	RDS(on)1	$V_{GS} = -10 V$ , $I_D = -13 A$		41	50	mΩ
	RDS(on)2	$V_{GS} = -4.0 \text{ V}, \text{ Id} = -13 \text{ A}$		55	79	mΩ
Input Capacitance	Ciss	$V_{DS} = -10 V$ ,		1900		pF
Output Capacitance	Coss	Vgs = 0 V,		350		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		140		pF
Turn-on Delay Time	td(on)	ID = -13 A,		9		ns
Rise Time	tr	$V_{GS(on)} = -10 V$ ,		10		ns
Turn-off Delay Time	td(off)	$V_{DD} = -30 V$ ,		67		ns
Fall Time	tr	$R_G = 0 \Omega$		19		ns
Total Gate Charge	Q <sub>G</sub>	$I_{D} = -25 A,$		38		nC
Gate to Source Charge	Q <sub>GS</sub>	$V_{DD}=-48 V$ ,		7		nC
Gate to Drain Charge	Qgd	V <sub>GS</sub> = -10 V		10		nC
Body Diode Forward Voltage	VF(S-D)	IF = -25 A, VGS = 0 V		1.0		V
Reverse Recovery Time	trr	IF = -25 A, VGS = 0 V		49		ns
Reverse Recovery Charge	Qrr	di/dt = $-100 \text{ A}/\mu \text{s}$		100		nC

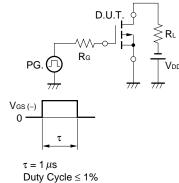
### TEST CIRCUIT 1 AVALANCHE CAPABILITY

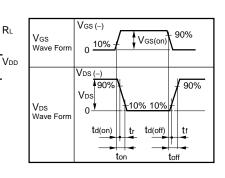
### **TEST CIRCUIT 2 SWITCHING TIME**



### **TEST CIRCUIT 3 GATE CHARGE**

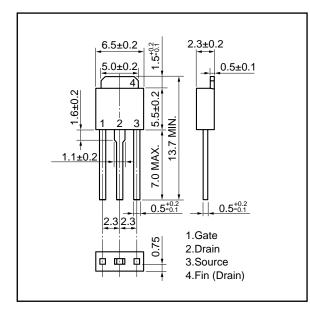


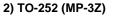


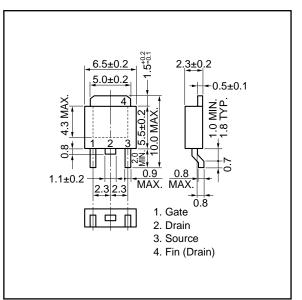


## PACKAGE DRAWINGS (Unit : mm)

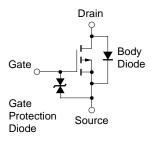
### 1) TO-251 (MP-3)







### **EQUIVALENT CIRCUIT**



**Remark** The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.  The information in this document is current as of November, 2000. The information is subject to change without notice. For actual design-in, refer to the latest publications of NEC's data sheets or data books, etc., for the most up-to-date specifications of NEC semiconductor products. Not all products and/or types are available in every country. Please check with an NEC sales representative for availability and additional information.

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